Low Energy Excess studies with CRYOSEL and RICOCHET detectors



Two discrimination techniques to reject events with no ionization

RICOCHET: charge measurement with a 1K HEMT preamplifier

EPJC 84 (2024) 186: arXiv : 2306.00166

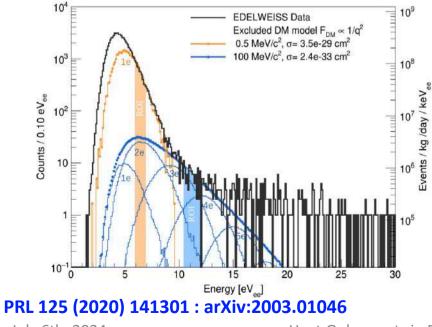
EDELWEISS CRYOSEL: Tagging Neganov-Luke-Trofimov phonons

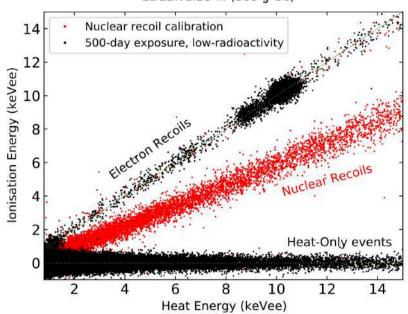
JTLP 215 (2024) 268 : arXiv:2311.01554

J. Gascon IP2I (Lyon1 + CNRS/IN2P3)

"Heat-Only" bkgs in cryogenic Ge detectors

- Main LEE in EDELWEISS 800g Ge heat-and-ionization detectors with Ge-NTD heat sensor
- Also for few-electron signal searches with 33g and 200g NTL-boosted Ge detectors





→ Charge identification essential to understand and reject LEE backgroundds

EDELWEISS-III (860 g Ge)

New Ge detectors for low energy searches

New detector designs evolved from EDELWEISS:

NbSi209 :

PRD 108 (2023) 022006 : arXiv:2303.02067

• 200g Ge + NbSi TES (instead of Ge-NTD), keeping EDELWEISS JFET ionization readout ($\sigma \sim$ 200 eVee)

RICOCHET CryoCube:

EPJC 84 (2024) 186: arXiv:2306.00166

 38g detector with Ge-NTD phonon sensor with 1-K HEMT charge readout (σ= 31 eV_{ee} achieved), for CENNS measurement

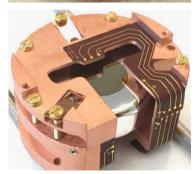




CRYOSEL

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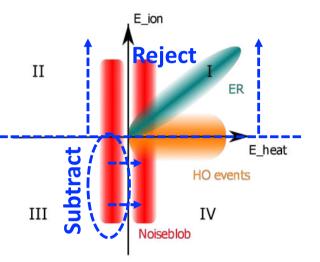
 38g detector with Ge-NTD phonon sensor with NTL boost and a charge tag using NbSi film as SSED (Superconducting Single-Electron Device)



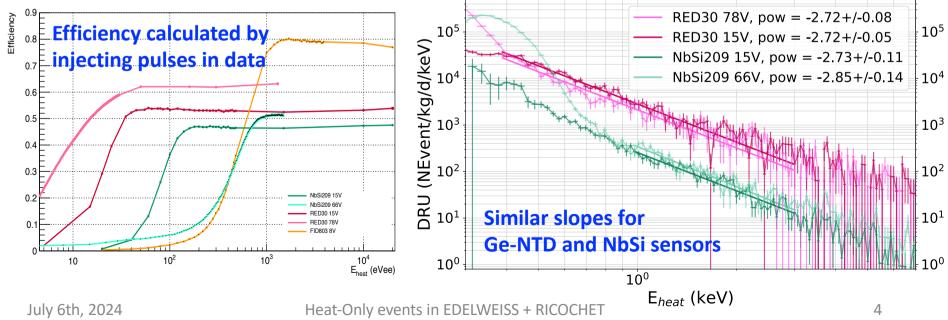
Low Energy Excess = Heat-Only?

- With σ =200 eV_{ee} ionization of EDELWEISS electronics, test of "heat-only" nature of events limited to ~1 keV_{ee}
- Comparison of HV/LV spectra
- Test of HO nature down to 15 eV_{ee} in RED30 (33g, 78V) and 35 eV_{ee} in NbSi209 (200g, 66V)

Below this: limited by noise blob from electronics

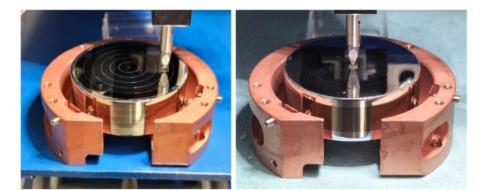


E. Guy, PhD thesis



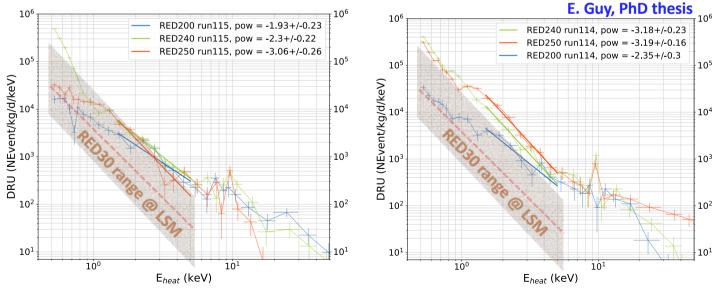
Ground-level measurements of HO in 38g Ge

- Test of HO rate at *ground-level* (Lyon) in 38g Ge RICOCHET detectors, using EDELWEISS electronics (σ_{ion} ~200 eV_{ee})
- Differences wrt LSM: reduced shielding, cosmic rays, differences in electrode schemes
- Large variations, but overall consistent with LSM 33 g (given known timedependence of HO rates)



RED200: 38 g, FID electrodes

RED240 + 250: 38 g, planar electrodes



HO event rates above ground are not a show-stopper

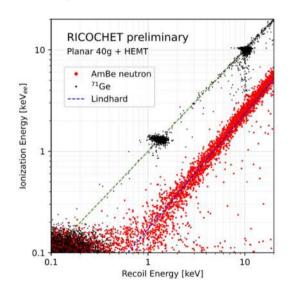
Measurements in low-background environment of ILL and HEMT readout to come soon!

July 6th, 2024

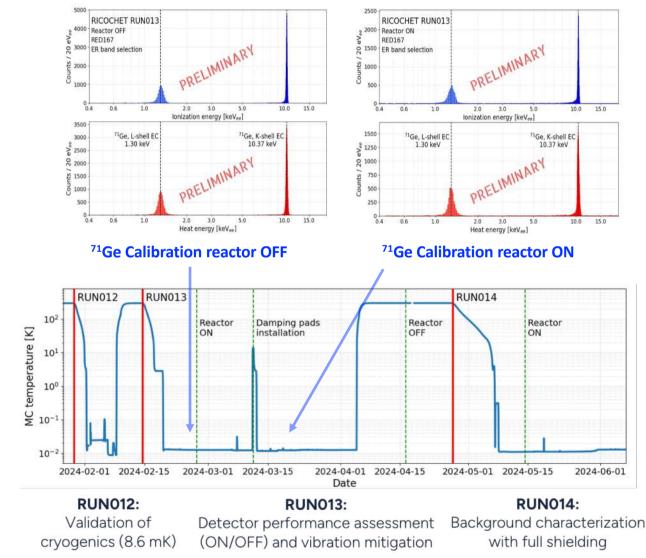
Heat-Only events in EDELWEISS + RICOCHET

RICOCHET Commissioning

2023-07: cryostat and HEMT commissioning @Lyon



2024: Commissioning @ ILL started!

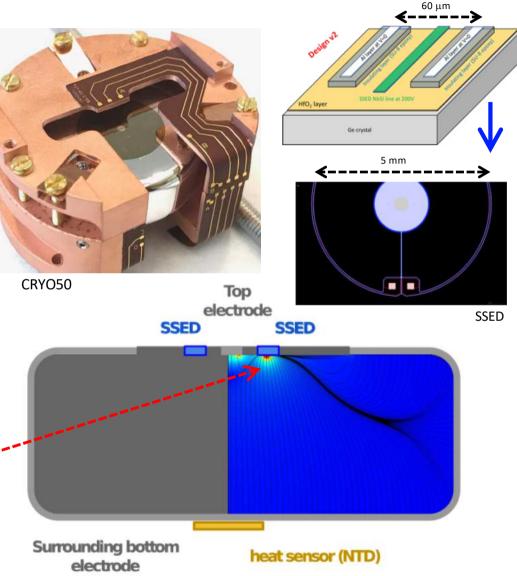


V. Novati, Neutrino 2024 N. Martini, Magnificent CENNS 2024

Heat-Only events in EDELWEISS + RICOCHET

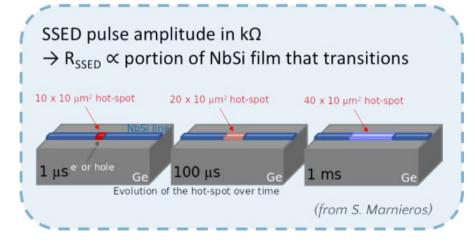
CRYOSEL concept : thermal + athermal

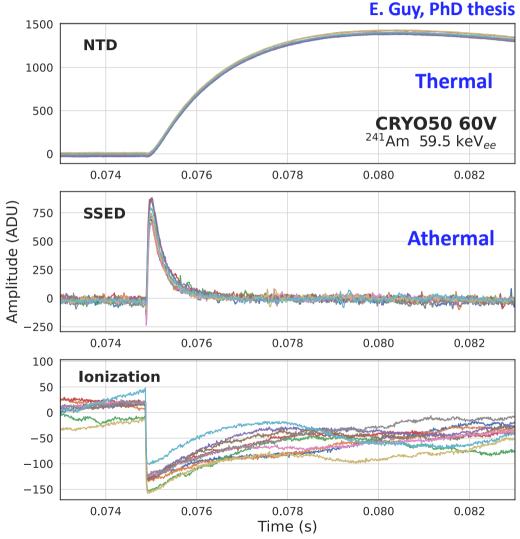
- 40 g Ge crystal
- Phonon sensor = single NbSi strip (10 μm wide) forming a 5 mm-wide circle
- Use this small film as Point-Contactlike electrode of HV detector
- NTD glued on large enveloping electrode (high-resolution NTLamplified heat measurement)
- NbSi operated as SSED (Superconducting Single-Electron Detector)
- Detector kept well below T_c : SSED only triggered by large bursts of primary NTL phonons from high field region just in front of it
- Most HO will not trigger SSED



SSED pulse shape

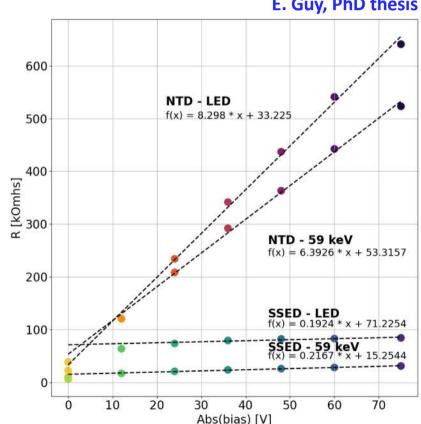
- CRYO50 prototype, $T_c = 46 \text{ mK}$
- 60V, T=15 mK (well below T_c)
- Pulses selected from NTD signal for 59.5 keV $^{\rm 241}{\rm Am}~\gamma$
- Slow thermal response of NTD
- Faster transition in part of SSED, followed by quick (<1ms) disappearance of this hot spot





SSED response to various excitations

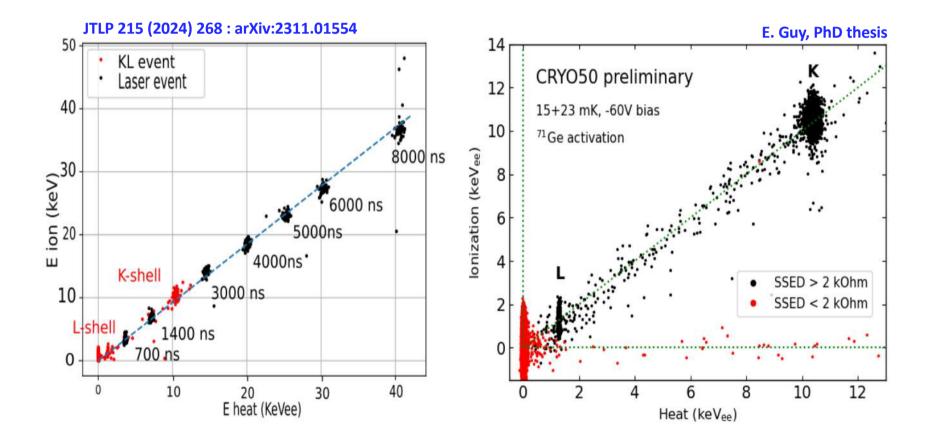
- 1650 nm IR laser or LED pulses (~diffuse bulk excitation), 1 to 300 keV
- ⁷¹Ge EC lines (point-like events in bulk, 1.3 and 10.37 keV)
- ²⁴¹Am collimated γ, 59.5 keV (surface)
- Fixed LED energy and ²⁴¹Am γ , variation of applied bias
- NTD signal increases with applied bias, as expected by NTL boost
- SSED signal ~saturates at a fraction of the total film resistance (1 M Ω)



E. Guy, PhD thesis

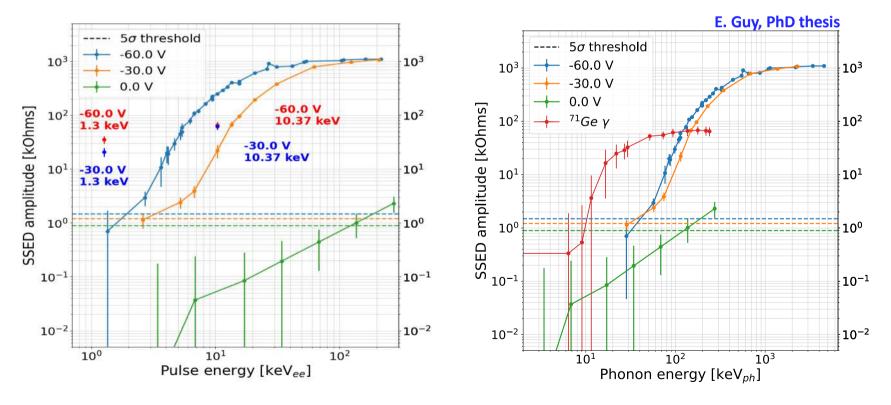
Peak energy resolution

 Despite huge variation of electric field inside the detector, the NTL boost is uniform for bulk events → good peak resolution



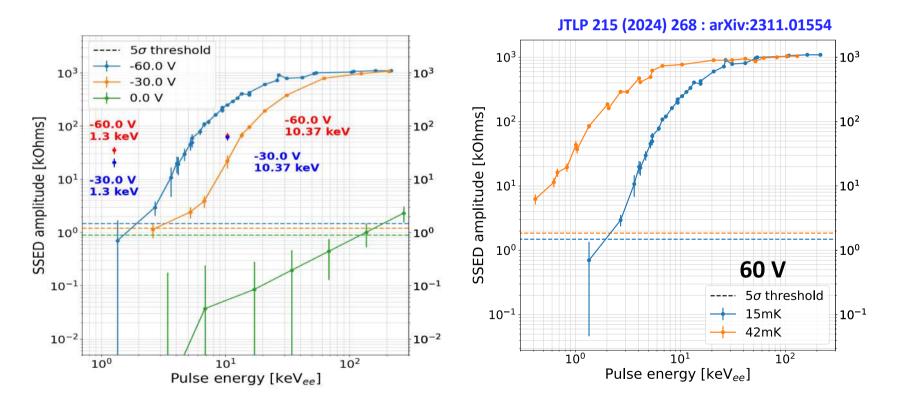
Response vs energy

- ~100 keV laser pulses can trigger transition in entire film (1 M Ω)
- Response ∝ total (init+NTL) phonon energy (not equivalent-electron): phonon detector!
- K + L lines saturate around ~70 k Ω : point-like excitations \rightarrow limited film section
- At low energy, point-like excitation trigger more efficiently than diffuse IR flux



Response vs $(T_c-T_{operation})$

- Annealing of NbSi film allow a reduction of Tc.
- Not done here on this first prototype: allow to study wide range of T_c-T_{operation}
- Threshold can be lowered by reducing T_c-T_{operation}



HO rejection

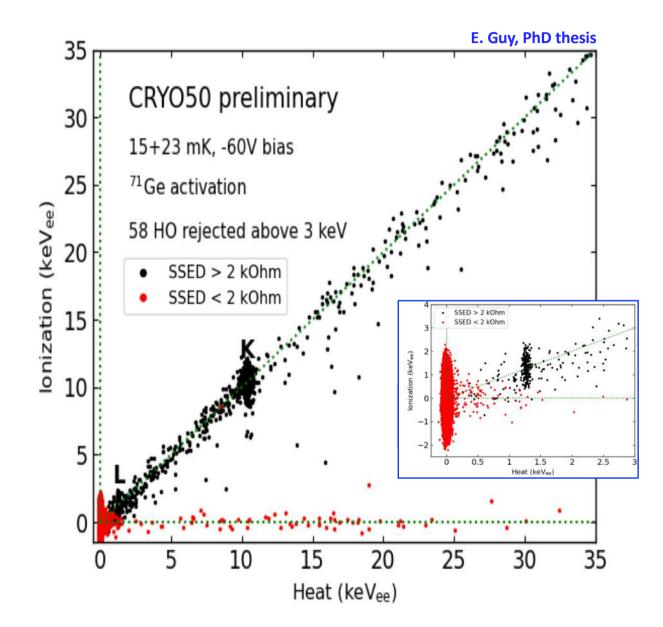
Cut on RSSED > 2 k Ω :

Rejection of all 58 heatonly events above 3 keV

>25 rejection @ 90%CL

The principle of identifying bulk ionizing events in a NTL-boosted detector using only NTL phonons works!

Next steps: higher bias, lower T_c, improve resolution



Conclusions

RICOCHET: Ionization readout with 1K HEMT preamplifier

- Ionization readout with 1K HEMT preamplifier
- Ongoing commissioning at ILL reactor
- Preliminary HO rate measurements in Lyon (noisier aboveground environment) consistent with previous measurements

CRYOSEL: Tagging NTL phonons with SSED:

- Superconducting NbSi strip sensitive to NTL phonons produced exclusively in nearby very-high field zone
- Principe of HO rejection confirmed
- Development for TESSERACT@LSM